

Claims

We Claim:

5 1. An electronic device package comprising:
 a support substrate including a flag, wherein the flag
 has bonding surface;
 a first electronic chip having a first peripheral edge,
 wherein the electronic chip is attached to a first portion
10 of the bonding surface with a first die attach material;
 a first continuous trench formed in the flag in
 proximity to the first peripheral edge, wherein the first
 continuous trench includes a curved sidewall surface and an
 inner edge adjacent to the first peripheral edge; and
15 an encapsulant covering the first electronic chip and
 at least a portion of the curved sidewall surface.

2. The package of claim 1, wherein the first
continuous trench surrounds the first electronic chip.

20 3. The package of claim 1, wherein the first
continuous trench comprises a continuously rounded cross-
sectional shape.

25 4. The package of claim 1, wherein the first
continuous trench has a cross-sectional shape comprising an
inverse omega shape.

30 5. The package of claim 1, wherein the first
continuous trench has a rounded corner.

6. The package of claim 1, wherein the first
continuous trench has depth in range from about 100 microns
to about 330 microns.

7. The package of claim 1, wherein the peripheral edge is substantially aligned with the inner edge of the first continuous trench.

5 8. The package of claim 1, wherein the first
peripheral edge is spaced a distance inside the inner edge
of the first continuous trench.

10 9. The package of claim 8, wherein the distance is
less than about 635 microns.

10. The package of claim 1, wherein the first
peripheral edge extends over the inner edge of the first
continuous trench.

15 11. The package of claim 1, wherein at least a portion
of the first die attach material extends to the inner edge
of the first continuous trench, and wherein the first
continuous trench is substantially absent die attach
20 material.

12. The package of claim 1 further comprising a second
trench formed in the flag, wherein the first electronic chip
overlies at least a portion of the second trench.

25 13. The package of claim 1, wherein the die attach
material is selected from a group consisting of a eutectic
solder, a solder paste, a conductive epoxy, a polyimide
film, a metal filled glass, and a pre-form structure.

30 14. The package of claim 1 further comprising:
a second electronic chip having a second peripheral
edge, wherein the second electronic chip is attached to a
second portion of the bonding surface with a second die
35 attach material; and

a second continuous trench formed in the flag in proximity to the second peripheral edge and around at least two sides of the second electronic chip, wherein the second continuous trench includes a curved sidewall surface
5 adjacent the second peripheral edge.

15. The package of claim 14 wherein the first and second continuous trenches have a common portion.

10 16. The package of claim 14 wherein the first and second die attach materials comprise different materials.

15 17. The package of claim 1, wherein the support substrate further includes a bonding site having a bonding surface, and wherein the package further comprises a bonding device coupling the first electronic chip to the bonding site, wherein the encapsulant covers the bonding device and the bonding surface of the bonding site.

20 18. The package of claim 1, wherein the first continuous trench comprises an etched trench.

19. A method for forming an electronic device package comprising the steps of:

25 providing a support substrate comprising a flag and a first trench formed in a bonding surface of the flag, wherein the first trench has a cross-sectional shape including a curved sidewall surface;

30 attaching a first electronic chip having a first peripheral edge to the bonding surface with a die attach material, wherein the first trench is in proximity to the first peripheral edge, and wherein the curved sidewall surface is adjacent the first peripheral edge; and

35 covering the first electronic chip and portions of the flag with a protective layer, wherein the protective layer covers at least a portion of the curved sidewall surface.

20. The method of claim 19 wherein the step of providing the support substrate includes providing a support substrate having a first trench that surrounds the first 5 peripheral edge.

21. The method of claim 19 wherein the step of providing the support substrate includes providing a support substrate having a first trench, wherein the first trench 10 has a continuously rounded cross-sectional shape.

22. The method of claim 19 wherein the step of attaching the first electronic chip to the bonding surface comprises the steps of:

15 placing the die attach material on a portion of the bonding surface bounded by the first trench; and

placing the first electronic chip on the die attach material, wherein the first trench prevents the die attach material from spreading beyond an inner edge of the first 20 trench to align the first electronic chip on the bonding surface.

23. The method of claim 19 wherein the step of covering comprises encapsulating the first electronic chip 25 and portion portions of the flag with a plastic encapsulant, wherein the plastic encapsulant extends into the first trench to provide a mold lock.

24. The method of claim 19 wherein the step of placing 30 the first electronic chip includes substantially aligning the first peripheral edge with an inner edge of the first trench.

25. The method of claim 19 wherein the step of placing 35 the first electronic chip includes placing the first

electronic chip wherein the first peripheral edge is spaced a distance inside an inner edge of the first trench.

26. The method of claim 25 wherein the step of placing
5 the first electronic chip includes placing the first
electronic chip a distance less than about 635 microns from
the inner edge of the first trench.

27. The method of claim 19 wherein the step of placing
10 the first electronic chip includes placing the first
electronic chip wherein the first peripheral edge extends
over an inner edge of the first trench.

28. The method of claim 19 wherein the step of
15 providing the support substrate includes the steps of:
 providing a leadframe having the flag with the bonding
 surface;
 masking the bonding surface to form a masking layer;
 selectively removing portions of the masking layer to
20 expose portions of the bonding surface; and
 etching the first trench into the bonding surface to
 provide the curved sidewall surface.

29. The method of claim 28 wherein the etching step
25 includes etching the first trench to provide an inverse
omega cross-sectional shape.

30. The method of claim 19 wherein the step of
providing the support substrate includes providing a support
30 substrate having a second trench formed in the bonding
surface, wherein the second trench has a cross-section shape
including curved sidewall surfaces.

31. The method of claim 30 further comprising the
35 steps of:

attaching a second electronic chip having a second peripheral edge to the bonding surface with a second die attach material, wherein the second trench is in proximity to the second peripheral edge; and

5 covering the second electronic chip and at least a portion of the curved sidewall surfaces of the second trench.

32. The method of claim 30 wherein the step of
10 providing the support substrate includes providing the support substrate wherein the first and second trenches have a common portion.

33. A leadless electronic structure comprising:
15 a leadframe including a bonding site and a flag having
a bonding surface;

a first semiconductor device having a first peripheral edge coupled to the bonding surface with a first chip attach layer, wherein the first semiconductor device includes a bond pad;

a first groove formed in the bonding surface surrounding the first semiconductor device, wherein the first groove comprises a substantially continuously curved inner surface and a first inner edge in proximity to the first peripheral edge, wherein at least a portion of first chip attach layer extends across the bonding surface and terminates at approximately the first inner edge;

a bonding device coupling the bond pad to the bonding site; and

30 an encapsulating layer covering exposed portions of the flag, the bonding site, and the bonding device, the first semiconductor device, and at least a portion of the substantially continuously curved inner surface.

34. The structure of claim 33 further comprising:

an electronic device having a second peripheral edge coupled to the bonding surface with a second chip attach layer; and

5 a second groove formed in the bonding surface surrounding the electronic device, wherein the second groove comprises a substantially continuously curved inner surface and a second inner edge in proximity to the second peripheral edge, and wherein at least a portion of the second chip attach layer extends across the bonding surface
10 and terminates at approximately the second inner edge.

35. The structure of claim 33 wherein the first chip attach layer comprises a conductive solder.

15 36. The structure of claim 33 wherein the first peripheral edge is placed an inner distance from the first inner edge.

20 37. The structure of claim 36 wherein the inner distance is less than about 635 microns.

38. The structure of claim 33 wherein the first peripheral edge is substantially aligned with the first inner edge.

25 39. The structure of claim 33 further comprising a shaped trench formed in the bonding surface, wherein the first semiconductor device overlies at least a portion of the shaped trench.

30 40. The structure of claim 39 wherein the shaped trench comprises a cross shape.

35 41. The structure of claim 39 wherein the shaped trench is connected to the first groove.

42. The structure of claim 33 wherein the first groove includes a rounded corner.